VS-E5TH1506THN3

Vishay Semiconductors

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Hyperfast Rectifier, 15 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I _{F(AV)}	15 A							
V _R	600 V							
V _F at I _F at 125 °C	1.15 V							
t _{rr} (typ.)	22 ns							
T _J max.	175 °C							
Package	TO-220AC 2L							
Circuit configuration	Single							

FEATURES

- · Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-220AC 2L Molding compound meets UL 94 V-0 flammability rating

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage	V _{RRM}		600	V					
Average rectified forward current	I _{F(AV)}	T _C = 136 °C, D = 0.50	15						
Repetitive peak forward current	I _{FRM}	T _C = 136 °C, D = 0.50, f = 20 kHz	30	А					
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	200						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	MIN.	TYP.	MAX.	UNITS					
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
Forward voltage	V _F	I _F = 15 A	-	1.3	1.6	6 V			
		I _F = 15 A, T _J = 125 °C	-	1.15	-				
Reverse leakage current	I _R	$V_{\rm R} = V_{\rm R}$ rated	-	-	10				
neverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated} - 5000$		500	μA				
Junction capacitance	CT	V _R = 200 V	-	25	-	pF			
Series inductance	Ls	Measured to lead 5 mm from package body	-	8	-	nH			



COMPLIANT



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		I _F = 1.0 A,dI _F /dt =	$I_F = 1.0 \text{ A,d}I_F/\text{dt} = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	31	-	ns			
		T _J = 125 °C		-	43	-				
Peak recovery current		T _J = 25 °C	I _F = 10 A dI _F /dt = 1000 A/µs	-	15	-	A			
	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	22	-				
Poweree receivery charge	0	T _J = 25 °C		-	255	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	622	-				
Deverse receiver time	+	T _J = 25 °C		-	38	-	ns			
Reverse recovery time	t _{rr}	T _J = 125 °C		-	49	-				
Deals receiver a current		T _J = 25 °C	I _F = 15 A dI _F /dt = 1000 A/µs	-	16	-	A			
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm B} = 400 \text{ V}$	-	24	-				
Devenue and evenue also and	0	T _J = 25 °C		-	316	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	782	-	nc			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.72	°C/W				
Weight			-	2.0	-	g				
weight			-	0.07	-	oz.				
Mounting torque			6.0 (5)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style 2L TO-220AC	E5TH1506TH							



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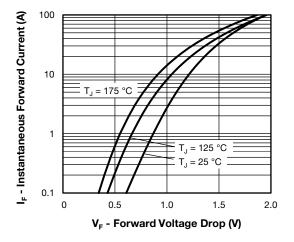


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

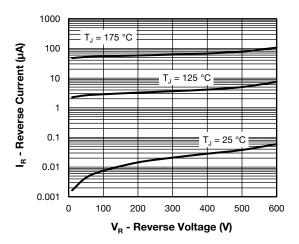
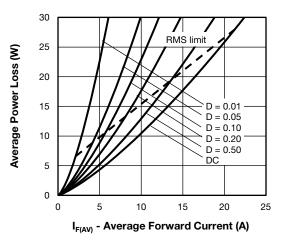
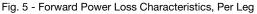


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg





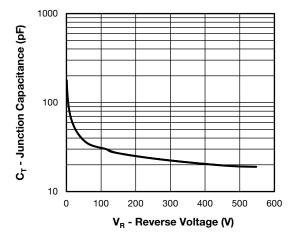


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

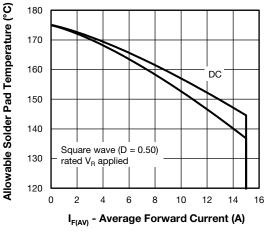


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

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VS-E5TH1506THN3 www.vishay.com **Vishay Semiconductors** 10 Z_{thJC} - Thermal Impedance Junction to Case (°C/W) 1 0.50 0.1 0.20 # 0.10 0.05 DC 0.02 0.01 0.01 0.00001 0.0001 0.001 0.01 0.1 t₁ - Rectangular Pulse Duration (s)

Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg

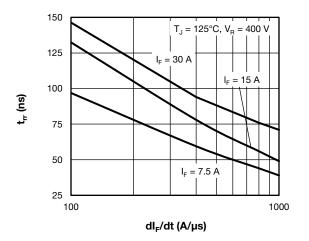


Fig. 7 - Typical Reverse Recovery Time vs. $dI_{\mbox{\scriptsize F}}/dt,$ Per Leg

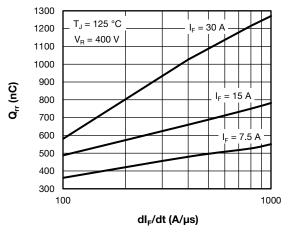


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

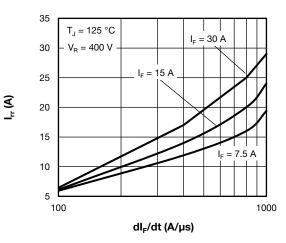


Fig. 9 - Typical Reverse Recovery Current vs. $dI_{\mbox{\rm F}}/dt,$ Per Leg

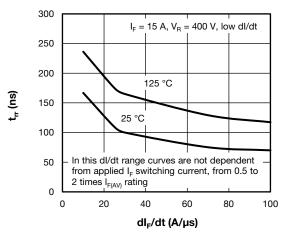


Fig. 10 - Typical Reverse Recovery Time vs. dI_F/dt , Per Leg

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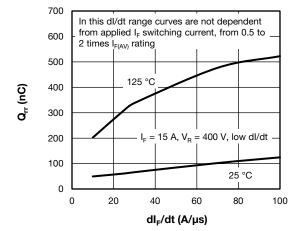
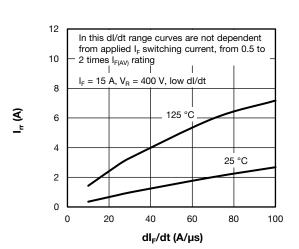


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg



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Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

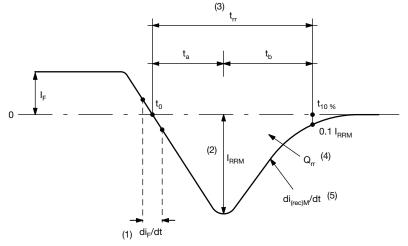


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$ peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

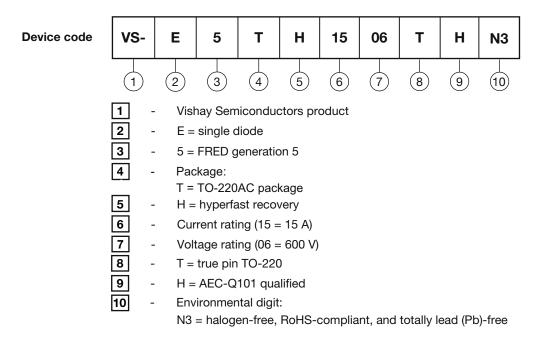


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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E5TH1506THN3	50	1000	Antistatic plastic tube					

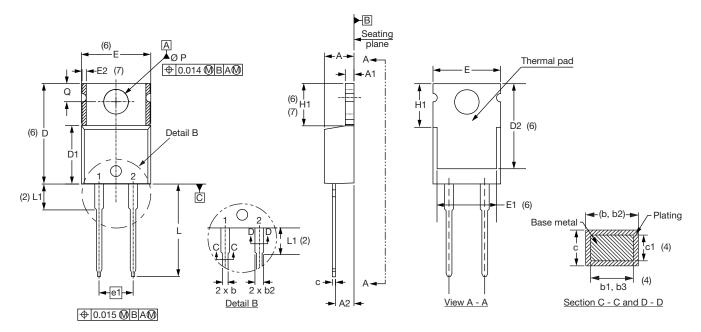
LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96069
Part marking information	www.vishay.com/doc?95391



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2L TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			e1	4.88	5.28	0.192	0.208	
b	0.69	1.01	0.027	0.040			H1	5.84	6.86	0.230	0.270	6, 7
b1	0.38	0.97	0.015	0.038	4		L	13.52	14.02	0.532	0.552	
b2	1.20	1.73	0.047	0.068			L1	3.32	3.82	0.131	0.150	2
b3	1.14	1.73	0.045	0.068	4		ØР	3.54	3.73	0.139	0.147	
с	0.36	0.61	0.014	0.024			Q	2.60	3.00	0.102	0.118	
c1	0.36	0.56	0.014	0.022	4							
D	14.85	15.25	0.585	0.600	3							
D1	8.38	9.02	0.330	0.355								
D2	11.68	12.88	0.460	0.507	6							
E	10.11	10.51	0.398	0.414	3, 6							

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

- $^{\left(7\right)}$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC[®] TO-220, except D2, where JEDEC[®] minimum is 0.480"

Revision: 09-Sep-2019

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